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Datasheet of TPS56221DQPT - IC REG BUCK ADJ 25A SYNC 22SON

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TPS56221

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TPS56221 4.5-V to 14-V Input, High-Current, Synchronous Buck SWIFT™ Converter

1 Features

- 4.5-V to 14-V Input Voltage Range
- Incorporates Power Block Technology
- Up to 25-A Output Current
- Fixed-Frequency Options of 300 kHz, 500 kHz, and 1 MHz
- High-Side and Low-Side MOSFET R_{DS(on)} Sensing
- · Programmable Soft-Start
- 600-mV Reference Voltage With 1% Accuracy
- Voltage Mode Control with Feed-Forward
- · Supports Prebiased Output
- Thermal Shutdown
- 22-Pin 5-mm x 6-mm PQFN PowerPAD™ Package
- For SWIFT[™] Power Products Documentation, see http://www.ti.com/swift

2 Applications

- · Point-of-Load (POL) Power Modules
- High-Density DC-DC Converters for Telecom and Networking Applications

3 Description

The TPS56221 device is a high-efficiency and high-current synchronous buck converter designed to operate from a supply from 4.5 V to 14 V. The device can produce an output voltage as low as 0.6 V at loads up to 25 A. Integrated NexFET™ Power MOSFETs provide a small footprint and ease of use.

The device implements a voltage-mode control with voltage feed-forward compensation that responds instantly to input voltage change.

The TPS56221 is available in a thermally enhanced 22-pin PQFN (DQP) PowerPAD package.

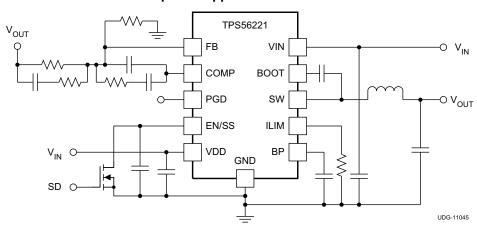
The device offers design flexibility with a variety of user programmable functions, including soft-start, overcurrent protection (OCP) levels, and loop compensation. OCP levels are programmed by a single external resistor connected from the ILIM pin to the circuit ground. During the initial power-on sequence, the device enters a calibration cycle, measures the voltage at the ILIM pin, and sets an internal OCP voltage level. During operation, the programmed OCP voltage level is compared to the voltage drop across the low-side FET when it is on to determine whether there is an overcurrent condition. It then enters a shutdown/restart cycle until the fault is removed.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
TPS56221	LSON-CLIP (22)	6.00 mm × 5.00 mm		

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Simplified Application Schematic





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TPS56221

SLUSAH5D -MARCH 2011-REVISED FEBRUARY 2016

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	i able c	or Conte	nts	
1	Features 1		7.3 Feature Description	10
2	Applications 1		7.4 Device Functional Modes	14
3	Description 1	8	Application and Implementation	15
4	Revision History2		8.1 Application Information	15
5	Pin Configuration and Functions 3		8.2 Typical Application	15
6	Specifications4	^	Power Supply Recommendations	22
-	6.1 Absolute Maximum Ratings 4	40	Layout	22
	6.2 ESD Ratings4		10.1 Layout Guidelines	<mark>22</mark>
	6.3 Recommended Operating Conditions 4		10.2 Layout Example	
	6.4 Thermal Information	11		
	6.5 Electrical Characteristics 5		11.1 Device Support	
	6.6 Typical Characteristics		11.2 Trademarks	
7	Detailed Description 10		11.3 Electrostatic Discharge Caution	
	7.1 Overview		11.4 Glossary	24
	7.2 Functional Block Diagram 10	12	Mechanical, Packaging, and Orderable Information	24
С	hages from Revision C (January 2015) to Revision D hanged the datasheet Title From: "TPS56221 4.5-V to o: "TPS56221 4.5-V to 14-V Input, High-Current, Synch			Page 1
	· · · · · · · · · · · · · · · · · · ·			
А	dded Features: " For SWIFT™ Power Products Docum	entation"		1
Char	nges from Revision B (September 2012) to Revision	С		Page
Λ	dded Pin Configuration and Functions section, ESD Ra Modes, Application and Implementation section, Power S and Documentation Support section, and Mechanical, Pa	Supply Rec	ommendations section, Layout section, Device	1
Char	ges from Revision A (JUNE 2012) to Revision B			Page
С	orrected typographical error in Equation 6			18
`hor	nges from Original (MARCH 2011) to Revision A			Page
	dded conditions to Electrical Characteristics table			
С	hanged characteristic data conditions			6
С	hanged Figure 15			9
С	hanged Figure 16			9
	hanged Figure 17			
	hanged Figure 18			
	dded Switching Node (SW) section			
()	hanged replaced design example			16

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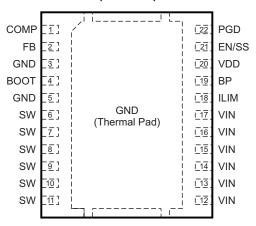
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5 Pin Configuration and Functions

DQP PACKAGE PQFN-22 (TOP VIEW)



Note: The thermal pad is also an electrical ground connection.

Pin Functions

P	PIN		DECODINE DE
NAME	NAME NO.		DESCRIPTION
воот	4	0	Gate drive voltage for the high-side FET. A 100-nF capacitor (typical) must be connected between this pin and the SW pin. To reduce a voltage spike at SW, a BOOT resistor between 5 Ω to 10 Ω may be placed in series with the BOOT capacitor to slow down turnon of the high-side FET.
BP	19	0	Output bypass for the internal regulator. Connect a low-ESR bypass ceramic capacitor of 1 μ F or greater from this pin to GND.
COMP	1	0	Output of the error amplifier and connection node for loop feedback components. Optionally, a 40.2-k Ω resistor from this pin to GND sets switching frequency to 300 kHz instead of the default value of 500 kHz; while a 13.3 k Ω resistor from this pin to GND sets switching frequency to 1 MHz.
EN/SS	21	I	Logic-level input starts or stops the controller via an external user command. Allowing this pin to float turns the controller on. Pulling this pin low disables the controller. This is also the soft-start programming pin. A capacitor connected from this pin to GND programs the soft-start time. The capacitor is charged with an internal current source of 10 μ A. The resulting voltage ramp of this pin is also used as a second noninverting input to the error amplifier after a 0.8 V (typical) level shift downwards. Output regulation is controlled by the internal level shifted voltage ramp until that voltage reaches the internal reference voltage of 600 mV. The voltage ramp of this pin reaches 1.4 V (typical).
FB	2	I	Inverting input to the error amplifier. In normal operation, the voltage on this pin is equal to the internal reference voltage.
GND	3 5	_	Ground reference for the device.
GND	Thermal Pad	_	Ground reference for the device. This is also the thermal pad used to conduct heat from the device. This connection serves two purposes. The first is to provide an electrical ground connection for the device. The second is to provide a low thermal impedance path from the device die to the PCB. This pad should be tied externally to a ground plane.
ILIM	18	I	A resistor connected from this pin to GND sets the overcurrent threshold for the device (the low-side FET).
PGD	22	0	Open-drain power good output.
	6		
	7		
CW	8		Switching node of the power conversion stage. Sense line for the adaptive anti-cross conduction circuitry.
SW	9	1	Acts as the common connection for the flying high-side FET driver.
	10		
	11		

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Pin Functions (continued)

PIN	ı	1/0	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
VDD	20	I	Power input to the controller. A low-ESR bypass ceramic capacitor of 1 μ F should be connected from this pin close to GND.
	12		
	13		
VIN	14		Power input to the high-side FET.
VIIN	15	'	Fower input to the high-side FET.
	16		
	17		

Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
	VDD, VIN	-0.3	16.5	
	SW	-3	25	
Valtage	SW (< 100 ns pulse width, 10 µJ)	- 5		V
Voltage	BOOT	-0.3	30	V
	BOOT-SW (differential from BOOT to SW)	-0.3	7	
	COMP, PGOOD, FB, BP, EN/SS, ILIM	-0.3	7	
Junction Tempera	ature, T _J	-40	150	°C
Storage temperature, T _{stq}		- 55	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those included under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods of time may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD) Electros	Electrostatio discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±2000	V
	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±1500	V

- JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
V_{DD}	VIN Input voltage	4.5	14	V
T_J	Operating junction temperature	-40	125	°C

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6.4 Thermal Information

		TPS56221	
	THERMAL METRIC ⁽¹⁾	PQFN	UNIT
		22 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	34.6	
R ₀ JC(top)	Junction-to-case (top) thermal resistance	22.9	
Ψлт	Junction-to-top characterization parameter	0.6	°C/W
ΨЈВ	Junction-to-board characterization parameter	5.0	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	0.3	

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report (SPRA953).

6.5 Electrical Characteristics

 $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}$, $\text{V}_{\text{VDD}} = 12 \text{ V}$, all parameters at zero power dissipation (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VOLTAGE RI	EFERENCE					
		$T_J = 25^{\circ}C, 4.5 \text{ V} \le V_{VDD} \le 14 \text{ V}$	597	600	603	
V_{FB}	FB input voltage	-40°C ≤ T _J ≤ 125°C, 4.5 V ≤ V _{VDD} ≤ 14 V	594	600	606	mV
INPUT SUPP	LY		1			
V_{VDD}	Input supply voltage range		4.5		14	V
IVDD _{SD}	Shutdown supply current	V _{EN/SS} = 0.2 V		80	120	μA
IVDD _Q	Quiescent, nonswitching	Let EN/SS float, V _{FB} = 1 V		2.5	5.0	mA
V _{UVLO}	UVLO ON Voltage		4.0		4.3	V
V _{UVLO(HYS)}	UVLO hysteresis		500		700	mV
ENABLE/SOI	FT-START					
V _{IH}	High-level input voltage, EN/SS		0.55	0.70	1.00	V
V _{IL}	Low-level input voltage, EN/SS		0.27	0.30	0.33	V
I _{SS}	Soft-start source current		8	10	12	μA
V _{SS}	Soft-start voltage level – start of ramp		0.4	0.8	1.3	V
BP REGULA	TOR		1		1	
V _{BP}	Output voltage	I _{BP} = 10 mA	6.2	6.5	6.8	V
V _{DO}	Regulator dropout voltage, V _{VDD} – V _{BP}	I _{BP} = 25 mA, V _{VDD} = 4.5 V		70	125	mV
OSCILLATOR	R		•			
		$R_{COMP} = 40.2 \text{ k}\Omega,$ $4.5 \text{ V} \le V_{VDD} \le 14 \text{ V}$	270	300	330	kHz
f _{SW}	Switching frequency	R_{COMP} = open, 4.5 V \leq V _{VDD} \leq 14 V	450	500	550	kHz
		R_{COMP} = 13.3 kΩ, 4.5 V ≤ V _{VDD} ≤ 14 V	0.8	0.95	1.1	MHz
V _{RAMP} ⁽¹⁾	Ramp amplitude		V _{VDD} /6.6	V _{VDD} /6	V _{VDD} /5.4	V
PWM					"	
		$f_{SW} = 300 \text{ kHz}, V_{FB} = 0 \text{ V},$ 4.5 V \leq V_{VDD} \leq 14 V	93%			
D _{MAX} ⁽¹⁾	Maximum duty cycle	$f_{sw} = 500 \text{ kHz}, V_{FB} = 0 \text{ V},$ 4.5 V \leq V_{VDD} \leq 14 V	90%			
		f _{sw} = 1 MHz, V _{FB} = 0 V, 4.5 V ≤ V _{VDD} ≤ 14 V	85%			
t _{ON(min)} (1)	Minimum controllable pulse width				100	ns

(1) Ensured by design. Not production tested

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Electrical Characteristics (continued)

-40°C $\leq T_J \leq 125$ °C, $V_{VDD} = 12$ V, all parameters at zero power dissipation (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
ERROR AMPL	IFIER					
GBWP (1)	Gain bandwidth product		10	24		MHz
A _O L ⁽¹⁾	Open loop gain		60			dB
I _{IB}	Input bias current (current out of FB pin)	V _{FB} = 0.6 V			75	nA
I _{EAOP}	Output source current	V _{FB} = 0 V	1.5			mA
I _{EAOM}	Output sink current	V _{FB} = 1 V	1.5			mA
POWER GOO	D					
V _{OV}	Feedback upper voltage limit for PGOOD		655	675	700	mV
V _{UV}	Feedback lower voltage limit for PGOOD		500	525	550	mV
V _{PGD-HYST}	PGOOD hysteresis voltage at FB			30	45	mV
R _{PGD}	PGOOD pull down resistance	V _{FB} = 0 V, I _{FB} = 5 mA		30	70	Ω
I _{PGDLK}	PGOOD leakage current	550 mV < V _{FB} < 655 mV, V _{PGOOD} = 5 V		10	20	μΑ
OUTPUT STA	GE					
R _{HI}	High-side device resistance	$T_J = 25$ °C, $(V_{BOOT} - V_{SW}) = 5.5 \text{ V}$		4.5	6.5	mΩ
R _{LO}	Low side device resistance	T _J = 25°C		1.9	2.7	mΩ
	NT PROTECTION (OCP)					
t _{PSSC(min)} (1)	Minimum pulse time during short circuit			250		
t _{BLNKH} (1)	Switch leading-edge blanking pulse time (high-side detection)			150		ns
I _{OCH}	OC threshold for high-side FET	$T_J = 25$ °C, $(V_{BOOT} - V_{SW}) = 5.5 V$	45	54	65	Α
I _{ILIM}	ILIM current source	T _J = 25°C		10.0		μA
V _{OCLPRO} ⁽¹⁾	Programmable OC range for low side FET	T _J = 25°C	12		100	mV
t _{OFF}	OC retry cycles on EN/SS pin			4		Cycle
BOOT DIODE					,	
V_{DFWD}	Bootstrap diode forward voltage	I _{BOOT} = 5 mA		0.8		V
THERMAL SH	IUTDOWN					
T _{JSD} ⁽¹⁾	Junction shutdown temperature			145		٥C
T _{JSDH} (1)	Hysteresis			20		٥С

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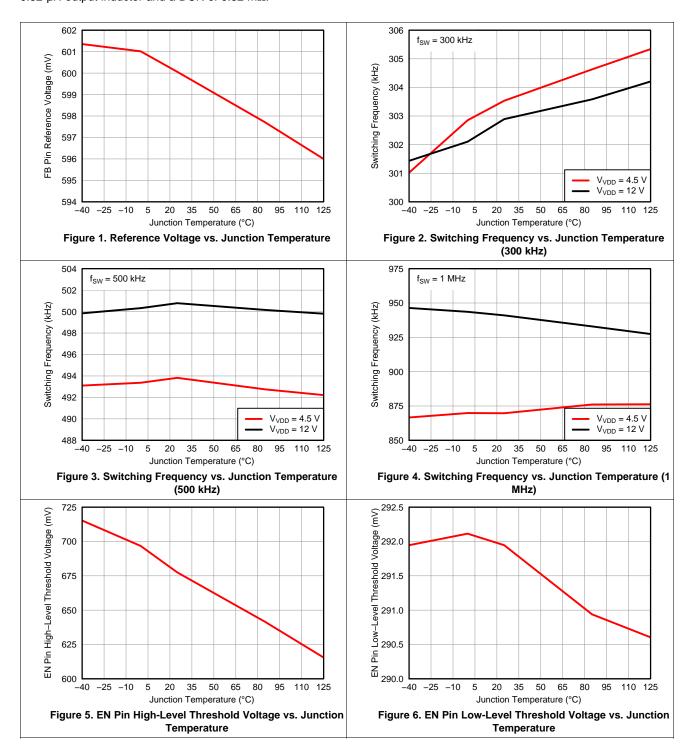


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6.6 Typical Characteristics

Figure 13 to Figure 18 are measured on a 2.5 inch \times 2.5 inch, 0.062 inch thick FR4 board with 4 layers and 2-oz. copper, a 0.32- μ H output inductor and a DCR of 0.32 m Ω .



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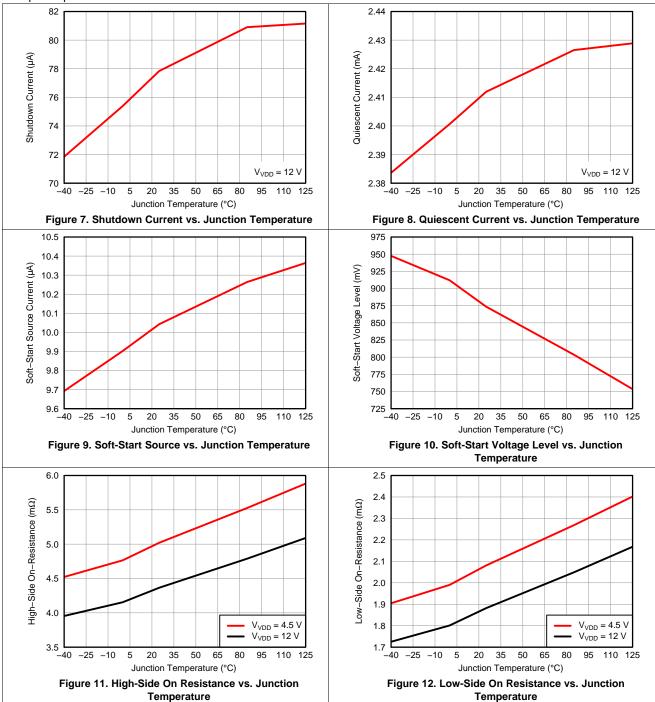
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Typical Characteristics (continued)

Figure 13 to Figure 18 are measured on a 2.5 inch \times 2.5 inch, 0.062 inch thick FR4 board with 4 layers and 2-oz. copper, a 0.32- μ H output inductor and a DCR of 0.32 m Ω .



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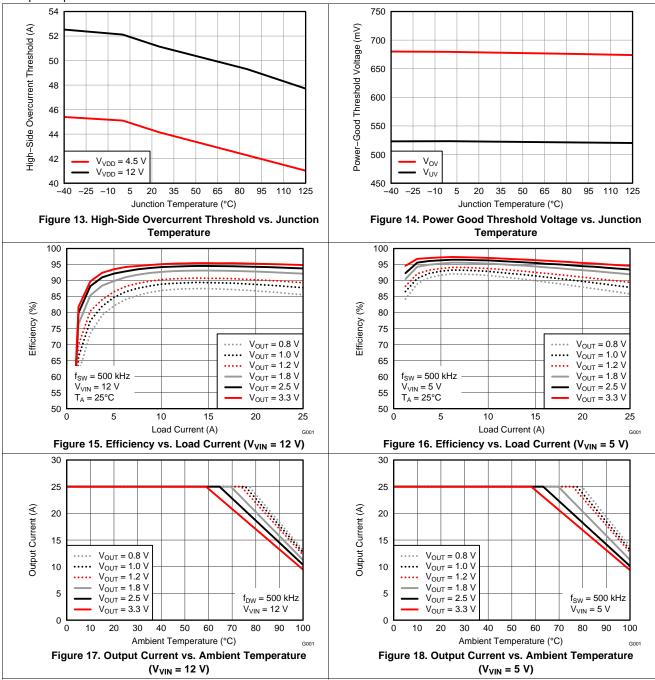
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Typical Characteristics (continued)

Figure 13 to Figure 18 are measured on a 2.5 inch x 2.5 inch, 0.062 inch thick FR4 board with 4 layers and 2-oz. copper, a 0.32- μH output inductor and a DCR of 0.32 m Ω .



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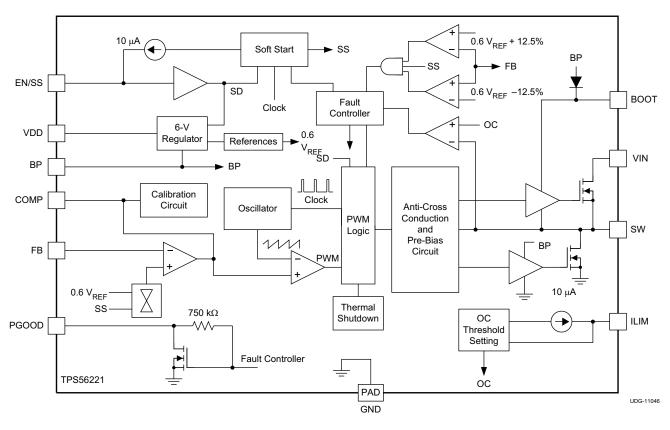
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7 Detailed Description

7.1 Overview

The TPS56221 is a 25-A high-performance synchronous buck converter with two integrated N-channel NexFET power MOSFETs. The device implements a voltage-mode control with voltage feed-forward compensation that responds instantly to input voltage change. Prebias capability eliminates concerns about damaging sensitive loads.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Voltage Reference

The 600-mV bandgap cell is internally connected to the noninverting input of the error amplifier. The reference voltage is trimmed with the error amplifier in a unity gain configuration to remove amplifier offset from the final regulation voltage. The 1% tolerance on the reference voltage allows the user to design a very accurate power supply.

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Feature Description (continued)

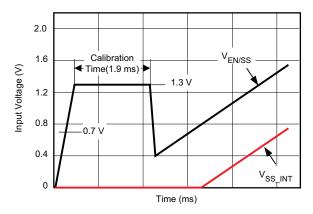


Figure 19. Start-Up Sequence and Timing

7.3.2 Enable Functionality, Start-Up, Sequence, and Timing

After input power is applied, an internal 40-µA current source begins to charge the soft-start capacitor connected from EN/SS to GND. When the voltage across that capacitor increases to 0.7 V, it enables the internal BP regulator followed by a calibration. Total calibration time is approximately 1.9 ms. See Figure 19. During the calibration, the device performs the following two functions.

7.3.2.1 COMP Pin Impedance Sensing

The device samples the impedance at the COMP pin and determines the appropriate operating switching frequency. If there is no resistor connected from the COMP pin to GND, the switching frequency is set to the default value of 500 kHz. If a resistor of 40.2 k Ω ± 10% is connected from the COMP pin to GND, the switching frequency is set to 300 kHz. Alternatively, if a resistor of 13.3 k Ω ± 10% is connected from the COMP pin to GND, the switching frequency is set to 1 MHz.

After a 1.1-ms time period, the COMP pin is then brought low for 0.8 ms. This ensures that the feedback loop is preconditioned at start-up and no sudden output rise occurs at the output of the converter when it is allowed to start switching.

7.3.2.2 Overcurrent Protection (OCP) Setting

The device sources 10 μ A (typical) to the resistor connected from the ILIM pin to GND. The voltage developed across that resistor multiplied by a factor of 2 is then sampled and latched off internally as the OCP trip level for the low-side FET until one cycles the input or toggles the EN/SS.

The voltage at EN/SS is internally clamped to 1.3 V before and/or during calibration to minimize the discharging time once calibration is complete. The discharging current is from an internal current source of 140 μ A and it pulls the voltage down to 0.4 V. It then initiates the soft-start by charging up the capacitor using an internal current source of 10 μ A. The resulting voltage ramp on this pin is used as a second noninverting input to the error amplifier after an 800 mV (typical) downward level-shift; therefore, the actual soft-start does not take place until the voltage at this pin reaches 800 mV.

If the EN/SS pin is left floating, the controller starts automatically. EN/SS must be pulled down to less than 270 mV to ensure that the chip is in shutdown mode.

7.3.3 Soft-Start Time

The soft-start time of the TPS56221 is user programmable by selecting a single capacitor. The EN/SS pin sources 10 μ A to charge this capacitor. The actual output ramp-up time is the amount of time that it takes for the 10 μ A to charge the capacitor through a 600 mV range. There is some initial lag due to calibration and an offset (800 mV) from the actual EN/SS pin voltage to the voltage applied to the error amplifier.

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Feature Description (continued)

The soft-start is accomplished in a closed-loop, meaning that the error amplifier controls the output voltage at all times during the soft-start period and the feedback loop is never open as occurs in duty cycle limit soft-start schemes. The error amplifier has two noninverting inputs, one connected to the 600-mV reference voltage, and the other connected to the offset EN/SS pin voltage. The lower of these two voltages is what the error amplifier controls the FB pin to. As the voltage on the EN/SS pin ramps up past approximately 1.4 V (800 mV offset voltage plus the 600 mV reference voltage), the 600-mV reference voltage becomes the dominant input and the converter has reached its final regulation voltage.

The capacitance required for a given soft-start ramp time for the output voltage is calculated in Equation 1.

$$C_{SS} = \left(\frac{I_{SS}}{V_{FB}}\right) \times t_{SS}$$

where

- C_{SS} is the required capacitance on the EN/SS pin (nF)
- I_{SS} is the soft-start source current (10 μA)
- V_{FB} is the feedback reference voltage (0.6 V)
- t_{SS} is the desired soft-start ramp time (ms)

(1)

7.3.4 Oscillator

The oscillator frequency is internally fixed at 500 kHz if there is no resistor connected from COMP pin to GND. Optionally, a 40.2-k Ω resistor from the COMP pin to GND sets the frequency to 300 kHz. Alternatively, a 13.3-k Ω resistor from COMP pin GND sets the frequency to 1 MHz.

7.3.5 Overcurrent Protection (OCP)

Programmable OCP level at ILIM is from 6 mV to 50 mV. With a scale factor of 2, the actual OC trip point across the low-side FET is in the range of 12 mV to 100 mV.

If the voltage drop across R_{OCSET} reaches 300 mV during calibration (No R_{OCSET} resistor included), it disables OC protection. Once disabled, there is no low-side or high-side current sensing.

OCP level for the high-side FET is fixed at 54 A (typical). The high-side OCP provides pulse-by-pulse current

OCP sensing for the low-side FET is a true inductor valley current detection, using sample and hold. Equation 2 can be used to calculate R_{OCSET}:

$$R_{OCSET} = \left(I_{OUT(max)} - \left(\frac{I_{P-P}}{2}\right)\right) \times 95 + 62.5$$

where

- I_{P-P} is the peak-to-peak inductor current (A)
- I_{OUT(max)} is the trip point for OCP (A)
- R_{OCSET} is the resistor used for setting the OCP level (Ω)

An overcurrent (OC) condition is detected by sensing voltage drop across the low-side FET and across the highside FET. If the voltage drop across either FET exceeds OC threshold, a count increments one count. If no OC condition is detected on either FET, the fault counter decrements by one counter. If three OC pulses are summed, a fault condition is declared which cycles the soft-start function in a hiccup mode. Hiccup mode is defined as four dummy soft-start time-outs followed by a real one if overcurrent condition is encountered during normal operation; or five dummy soft-start time-outs followed by a real one if overcurrent condition occurs from the beginning during start. This cycle continues indefinitely until the fault condition is removed.



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Feature Description (continued)

7.3.6 Switching Node (SW)

The SW pin connects to the switching node of the power conversion stage. It acts as the return path for the high-side gate driver. When configured as a synchronous buck stage, the voltage swing on SW normally traverses from below ground to well above the input voltage. Parasitic inductance in the high-side FET and the output capacitance (C_{OSS}) of both power FETs form a resonant circuit that can produce high frequency (> 100 MHz) ringing on this node. The voltage peak of this ringing, if not controlled, can be significantly higher than the input voltage. Ensure that the peak ringing amplitude does not exceed the absolute maximum rating limit for the pin.

In many cases, a series resistor and capacitor snubber network connected from the switching node to PGND can be helpful in damping the ringing and decreasing the peak amplitude. Provide provisions for snubber network components in the layout of the printed circuit board. If testing reveals that the ringing amplitude at the SW pin exceeds the limit, then include snubber components.

Placing a BOOT resistor with a value from 5 Ω to 10 Ω in series with the BOOT capacitor slows down the turnon of the high-side FET and can help to reduce the peak ringing at the switching node.

7.3.7 Input Undervoltage Lockout (UVLO)

The TPS56221 has fixed input UVLO. In order for the device to turn on, the following conditions must be met:

- The EN/SS pin voltage must be greater than V_{IH}
- The input voltage must exceed UVLO on voltage V_{UVLO}

The UVLO has a minimum of 500 mV hysteresis built-in.

7.3.8 Prebias Start-Up

The TPS56221 contains a unique circuit to prevent current from being pulled from the output during start-up in the condition the output is prebiased. There are no PWM pulses until the internal soft-start voltage rises above the error amplifier input (FB pin), if the output is prebiased. Once the soft-start voltage exceeds the error amplifier input, the controller slowly initiates synchronous rectification by starting the synchronous rectifier with a narrow on time. It then increments the on-time on a cycle-by-cycle basis until it coincides with the time dictated by (1–D), where D is the duty cycle of the converter.

This approach prevents the sinking of current from a prebiased output, and ensures the output voltage start-up and ramp to regulation is smooth and controlled.

7.3.9 Power Good

The TPS56221 provides an indication that output is good for the converter. This is an open-drain signal and pulls low when any condition exists that would indicate that the output of the supply might be out of regulation. These conditions include:

- V_{FB} is more than ±12.5% from nominal
- · soft-start function is active
- · a short-circuit condition has been detected

NOTE

When there is no power to the device, PGOOD cannot pull close to GND if an auxiliary supply is used for the power good indication. In this case, a built-in resistor connected from drain to gate on the PGOOD pulldown device makes the PGOOD pin look approximately like a diode to GND.

7.3.10 Thermal Shutdown

If the junction temperature of the device reaches the thermal shutdown limit of 145°C, both high-side FET and low-side FET are kept off. When the junction cools to the required level (125°C typical), the PWM initiates soft start as during a normal power-up cycle.



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7.4 Device Functional Modes

The TPS56221 devices operate in continuous conduction mode (CCM) at a fixed frequency, regardless of the output current. For the first 128 switching cycles, the low-side MOSFET on-time is slowly increased to prevent excessive current sinking in the event the device is started with a prebiased output. Following the first 128 switching cycles, the low-side MOSFET and the high-side MOSFET on-times are fully complementary.

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8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TPS56221 is highly integrated synchronous step-down DC-DC converters. The device is used to convert a higher DC input voltage (4.5 V to 14 V recommended) to a lower DC output voltage (as low as 0.6 V), with a maximum output current of 25 A, for a variety of applications. Use the following design procedure to select key component values for this device.

8.2 Typical Application

This design example describes a 25-A, 12-V to 1.0-V design using the TPS56221 high-current integrated buck converter. The system specifications are listed in Table 1.

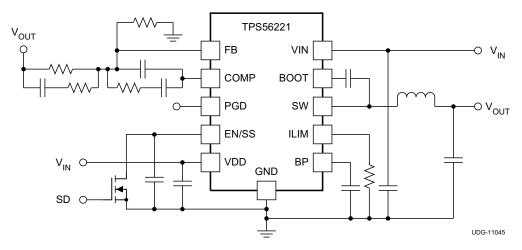


Figure 20. Typical Application Schematic



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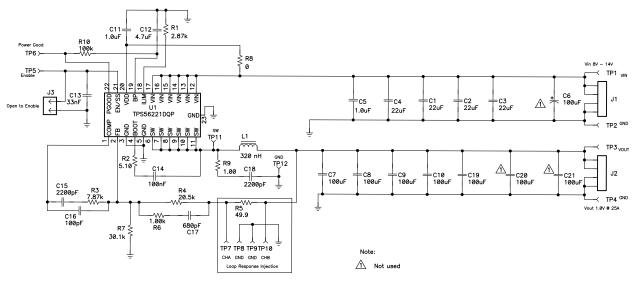


Figure 21. Design Example Schematic

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8.2.1 Design Requirements

Table 1. Design Example Parameters

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IN}	Input voltage		8.0		14	V
V _{IN(ripple)}	Input ripple	I _{OUT} = 25 A			0.2	V
V _{OUT}	Output voltage	0 A ≤ I _{OUT} ≤ 25 A	0.98	1.00	1.02	V
	Line regulation	8 V ≤ V _{IN} ≤ 14 V			0.1%	
	Load regulation	0 A ≤ I _{OUT} ≤ 25 A			1.0%	
V _{P-P}	Output ripple	I _{OUT} = 25 A		20		mV
V _{OVER}	Output overshoot	I _{TRAN} = 10 A		100		mV
V _{UNDER}	Output undershoot	I _{TRAN} = 10 A		100		mV
I _{OUT}	Output current	8 V ≤ V _{IN} ≤ 14 V	0		25	Α
t _{SS}	Softstart time	V _{IN} = 12 V		2.0		ms
I _{SCP}	Short circuit current trip point		32			Α
η	Efficiency	V _{IN} = 12 V, I _{OUT} = 25 A		87%		
f _{SW}	Switching frequency			500		kHz

8.2.2 Detailed Design Procedure

Table 2. List of Materials for TPS56221 Design Example

REFERENCE DESIGNATOR	QTY	VALUE	DESCRIPTION	SIZE	PART NUMBER	MANUFACTURER
C1, C2, C3, C4	4	22 µF	Capacitor, Ceramic, 25 V, X5R, 20%	1210	Std	Std
C5, C11	2	1.0 µF	Capacitor, Ceramic, 25 V, X7R, 20%	0805	Std	Std
C6	0	100 μF	Capacitor, Ceramic, 16 Vdc, ±20%	Code D8	Std	EEEFP1C101AP
C7, C8, C9, C10, C19	5	100 μF	Capacitor, Ceramic, 6.3 V, X5R, 20%	1210	Std	Std
C12	1	4.7 µF	Capacitor, Ceramic, 10 V, X5R, 20%	0805	Std	Std
C13	1	33 nF	Capacitor, Ceramic, 16 V, X7R, 20%	0603	Std	Std
C14	1	100 nF	Capacitor, Ceramic, 16V, X7R, 20%	0402	Std	Std
C15, C18	2	2200 pF	Capacitor, Ceramic, 50 V, X7R, 10%	0603	Std	Std
C16	1	100 pF	Capacitor, Ceramic, 50 V, C0G, 10%	0603	Std	Std
C17	1	680 pF	Capacitor, Ceramic, 50 V, C0G, 10%	0603	Std	Std
C20, C21	0	100 μF	Capacitor, Ceramic, 6.3 V, X5R, 20%	1210	Std	Std
J1, J2	2		Terminal Block, 4-pin, 15-A, 5.1 mm	0.80 x 0.35 inch	ED120/4DS	
J3	1		Header, Male 2-pin, 100 mil spacing	0.100 inch x 2	PEC02SAAN	
L1	1	320 nH	Inductor, 320 nH, 41 A, 0.32 mΩ	0.530 x 0.510 inch	PA2202-321NL	Pulse
R1	1	1.78 kΩ	Resistor, Chip, 1/16W, 1%	0603	Std	Std
R2	1	5.10 Ω	Resistor, Chip, 1/16W, 1%	0603	Std	Std
R3	1	7.87 kΩ	Resistor, Chip, 1/16W, 1%	0603	Std	Std
R4	1	20.5 kΩ	Resistor, Chip, 1/16W, 1%	0603	Std	Std
R5		49.9Ω	Resistor, Chip, 1/16W, 1%	0603		
R6	1	1.00 kΩ	Resistor, Chip, 1/16W, 1%	0603	Std	Std
R7	1	30.1 kΩ	Resistor, Chip, 1/16W, 1%	0603	Std	Std
R8	1	0 Ω	Resistor, Chip, 1/16W, 1%	0603		
R9	1	1 Ω	Resistor, Chip, 1/16W, 1%	0603		
R10	1	100 kΩ	Resistor, Chip, 1/16W, 1%	0603		

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Table 2. List of Materials for TPS56221 Design Example (continued)

REFERENCE DESIGNATOR	QTY	VALUE	DESCRIPTION	SIZE	PART NUMBER	MANUFACTURER
TP1, TP3, TP11	3		Test Point, Red, Thru Hole	0.125 x 0.125 inch	5010	
TP2, TP4, TP8, TP9, TP12	5		Test Point, Black, Thru Hole	0.125 x 0.125 inch	5011	
TP5, TP6	2		Test Point, Yellow, Thru Hole	0.125 x 0.125 inch	5014	
TP7, TP10	2		Test Point, White, Thru Hole	0.125 x 0.125 inch	5012	
U1	1	QFN-22	4.5-V to 14-V Input, 25-A, synchronous buck converter	6 × 5 mm	TPS56221DQP	TI

8.2.2.1 Switching Frequency Selection

To achieve a balance between small size and high efficiency for this design, use switching frequency of 500 kHz.

8.2.2.2 Inductor Selection

Synchronous buck power inductors are typically sized for between approximately 20% and 40% peak-to-peak ripple current (I_{P-P}).

Using this target ripple current, the required inductor size can be calculated as shown in Equation 3.

$$L \approx \frac{V_{IN(max)} - V_{OUT}}{0.3 \times I_{OUT}} \times \frac{V_{OUT}}{V_{IN(max)}} \times \frac{1}{f_{SW}} = \frac{14 \, V - 1.0 \, V}{0.3 \times 25 \, A} \times \frac{1.0 \, V}{14 \, V} \times \frac{1}{500 \, kHz} = 186 \, nH \tag{3}$$

Selecting a standard 320-nH inductor value, $I_{P-P} = 5.8 \text{ A}$.

The RMS current through the inductor is approximated in Equation 4.

$$I_{L(rms)} = \sqrt{\left(I_{L(avg)}\right)^{2} + \left(I_{12} \times \left(I_{RIPPLE}\right)^{2}\right)} = \sqrt{\left(I_{OUT}\right)^{2} + \left(I_{12} \times \left(I_{P-P}\right)^{2}\right)} = \sqrt{\left(25\right)^{2} + \left(I_{12} \times \left(5.8\right)^{2}\right)} = 25.06 \text{ A}$$
(4)

8.2.2.3 Output Capacitor Selection

The selection of the output capacitor is typically driven by the output transient response. For applications with $V_{IN(min)} > 2 \times V_{OUT}$, use overshoot to calculate the minimum output capacitance and the equation is shown in Equation 5.

$$C_{OUT(min)} = \frac{(I_{TRAN})^2 \times L}{V_{OUT} \times V_{OVER}} = \frac{(10)^2 \times 320 \text{ nH}}{1.0 \times 100 \text{ mV}} = 320 \,\mu\text{F}$$
 (5)

For applications where $V_{IN(min)}$ < 2 x V_{OUT} , use undershoot to calculate minimum output capacitance. The equation is shown in Equation 6.

$$C_{OUT(min)} = \frac{(I_{TRAN})^2 \times L}{(V_{IN} - V_{OUT}) \times V_{UNDER}}$$
(6)

To meet the low ESR and high-capacitance requirements of this design, five $100-\mu F$, 1210 ceramic capacitors are selected. With a minimum capacitance, the maximum allowable ESR is determined by the maximum ripple voltage and is approximated by Equation 7.

$$ESR_{COUT(max)} = \frac{V_{RIPPLE} - V_{RIPPLE(COUT)}}{I_{P-P}} = \frac{V_{RIPPLE} - \left(\frac{I_{P-P}}{8 \times C_{OUT} \times f_{SW}}\right)}{I_{P-P}} = \frac{20 \, \text{mV} - \left(\frac{5.8 \, \text{A}}{8 \times 500 \, \mu \text{F} \times 500 \, \text{kHz}}\right)}{5.8 \, \text{A}} = 2.9 \, \text{m} \Omega$$

$$(7)$$

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8.2.2.4 Inductor Peak Current Rating

With output capacitance, it is possible to calculate the charge current during start-up and determine the minimum saturation current rating for the inductor. The start-up charging current is approximated by Equation 8.

$$I_{CHARGE} = \frac{V_{OUT} \times C_{OUT}}{t_{SS}} = \frac{1.0 \text{ V} \times 500 \,\mu\text{F}}{2 \text{ms}} = 0.25 \,\text{A} \tag{8}$$

The peak current in the inductor $I_{L(peak)}$ is approximated by Equation 9.

$$I_{L(peak)} = I_{OUT(max)} + (\frac{1}{2} \times I_{RIPPLE}) + I_{CHARGE} = 25 \text{ A} + (\frac{1}{2} \times 5.8 \text{ A}) + 0.25 \text{ A} = 28.2 \text{ A}$$
(9)

With the short circuit current trip point $I_{OUT(max)}$ set at 32 A, the maximum allowable peak current $I_{L(peak\ max)}$ is

$$I_{L(peak max)} = I_{OUT(max)} + (\frac{1}{2} \times I_{RIPPLE}) = 30 \text{ A} + (\frac{1}{2} \times 5.8 \text{ A}) = 32.9 \text{ A}$$
 (10)

The selection of output capacitor meets the maximum allowable peak current requirement.

Table 3. Inductor Requirements Summary

	VALUE	UNIT	
L	Inductance	320	nH
I _{L(rms)}	RMS current (thermal rating)	25.1	Α
I _{L(peak max)}	Peak current (saturation rating)	32.9	Α

The PA0513.321NLT, 320-nH, 0.32-mΩ, 41-A inductor is selected.

8.2.2.5 Input Capacitor Selection

The input voltage ripple is divided between capacitance and ESR. For this design $V_{IN_RIPPLE(CAP)} = 150$ mV and $V_{IN_RIPPLE(ESR)} = 50$ mV. The minimum capacitance and maximum ESR are estimated in Equation 11.

$$C_{IN(min)} = \frac{I_{OUT} \times V_{OUT}}{V_{IN_RIPPLE(CAP)} \times V_{IN(min)} \times f_{SW}} = \frac{25 \times 1.0 \text{V}}{150 \, \text{mV} \times 8 \, \text{V} \times 500 \, \text{kHz}} = 41.7 \, \mu\text{F}$$

$$(11)$$

$$ESR_{CIN(max)} = \frac{V_{IN_RIPPLE(ESR)}}{I_{OUT} + \frac{1}{2}(I_{P-P})} = \frac{50\,\text{mV}}{25A + \frac{1}{2}(5.8A)} = 1.8\,\text{m}\Omega \tag{12}$$

The RMS current in the input capacitors is estimated by Equation 13.

$$I_{RMS(cin)} = I_{LOAD} \times \sqrt{D \times (1-D)} = 25 \text{ A} \times \sqrt{\frac{1}{8} \times \left(1 - \frac{1}{8}\right)} = 8.3 \text{ A}_{RMS}$$
(13)

Four 1210, 22-μF, 25-V, X5R ceramic capacitors with about 2.5-mΩ of ESR and a 2.5-A RMS current rating are selected. Higher voltage capacitors are selected to minimize capacitance loss at the DC bias voltage to ensure the capacitors will have sufficient capacitance at the working voltage while a 1.0-μF capacitor in smaller case size is used to reduce high frequency noise from the MOSFET switching.

8.2.2.6 Boot-Strap Capacitor (C14)

The bootstrap capacitor maintains power to the high-side driver during the high-side switch ON time. Per the requirements of the integrated MOSFET, C_{BOOT} is 100 nF with a minimum 10-V rating.

8.2.2.7 Boot-Strap Resistor (R2)

The bootstrap resistor slows the rising edge of the SW voltage to reduce ringing and improve EMI. Per the datasheet recommendation a $5.10-\Omega$ resistor is selected.

8.2.2.7.1 RC Snubber (R9 and C18)

To effectively limit the switch node ringing, a 1.0-Ω resistor and a 2200-pF capacitor are selected.

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8.2.2.8 VDD Bypass Capacitor (C11)

In accordance with pin terminations recommended in the data sheet, VDD is bypassed to GND with a 1.0-µF capacitor.

8.2.2.9 BP5 Bypass Capacitor (C12)

Per the datasheet recommended pin terminations, BP5 is bypassed to GND with at least 1.0-μF capacitor. For additional filtering and noise immunity a 4.7-μF capacitor is selected.

8.2.2.10 Soft-Start Capacitor (C13)

The soft-start capacitor provides a constant ramp voltage to the error amplifier to provide controlled, smooth start-up. The soft-start capacitor is sized using Equation 14.

$$C_{SS} = \frac{I_{SS}}{V_{FB}} \times t_{SS} = \frac{10 \,\mu\text{A}}{0.6 \,\text{V}} \times 2.0 \,\text{ms} = 33 \,\text{nF}$$
 (14)

8.2.2.11 Current Limit (R1)

The TPS56221 uses the negative drop across the internal low-side FET at the end of the OFF-time to measure the valley of the inductor current. Allowing for a minimum of 30% over maximum load, the programming resistor is selected using Equation 15.

$$R_{OCSET} = 95 \times \left(I_{OUT(max)} - \left(\frac{I_{P-P}}{2}\right)\right) + 62.5 \Omega = 95 \times \left(30 \text{ A} - \left(\frac{5.8 \text{ A}}{2}\right)\right) + 62.5 \Omega = 2.83 \text{ k}\Omega$$
(15)

A standard 2.87-k Ω resistor is selected from the E-48 series.

8.2.2.12 Feedback Divider (R4, R7)

The TPS56221 converter uses a full operational amplifier with an internally fixed 0.600-V reference. R4 is selected between 10 k Ω and 50 k Ω for a balance of feedback current and noise immunity. With R4 set to 20.5 k Ω , The output voltage is programmed with a resistor divider given by Equation 16.

$$R7 = \frac{V_{FB} \times R4}{\left(V_{OUT} - V_{FB}\right)} = \frac{0.600 \, \text{V} \times 20.5 \, \text{k}\Omega}{1.0 \, \text{V} - 0.600 \, \text{V}} = 30.8 \, \text{k}\Omega \tag{16}$$

A standard 30.1- $k\Omega$ resistor is selected from the E-48 series.

8.2.2.13 Compensation (C15, C16, C17, R3, R6)

Using the *TPS40k Loop Stability Tool* for 50 kHz of bandwidth and 60 degrees of phase margin with an R4 value of 20.5 $k\Omega$, the following values are obtained.

- C17 = C_1 = 680 pF
- C15 = C_2 = 2200 pF
- C16 = C_3 = 100 pF
- $R6 = R \ 2 = 1.00 \text{ k}\Omega$
- $R3 = R_3 = 7.87 \text{ k}\Omega$

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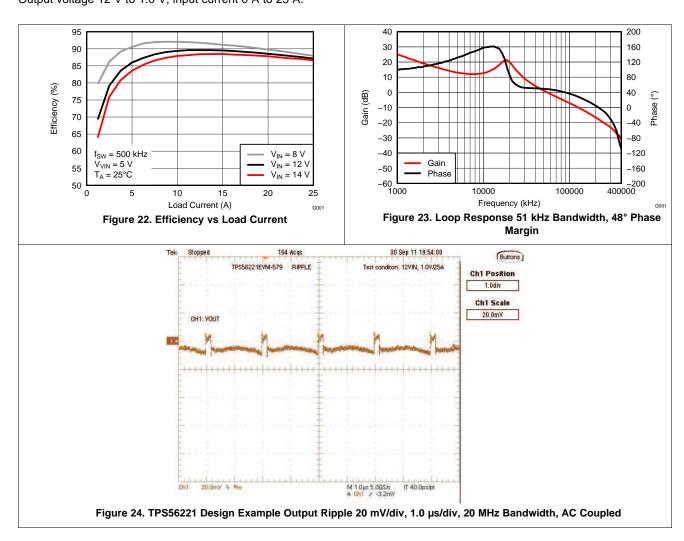
8.2.3 Application Curves

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Output voltage 12 V to 1.0 V, input current 0 A to 25 A.



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9 Power Supply Recommendations

The TPS56221 devices are designed to operate from an input voltage supply between 4.5 V and 14 V. This supply must be well regulated. These devices are not designed for split-rail operation. The VIN and VDD terminals must be the same potential for accurate high-side short circuit protection. Proper bypassing of input supplies and internal regulators is also critical for noise performance, as is PCB layout and grounding scheme. See the recommendations in *Layout Guidelines*.

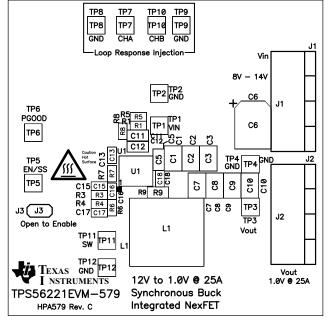
10 Layout

10.1 Layout Guidelines

- Place input capacitors next to the VIN pin and on the same side as the device. Use wide and short traces or copper planes for the connection from the VIN pin to the input capacitor and from the input capacitor to the power pad of the device.
- Place the BP decoupling capacitor close to the BP pin and on the same side as the device in order to avoid
 the use of vias. Use wide and short traces for the connection from the BP pin to the capacitor and from the
 capacitor to the power pad. If vias are not evitable, use at least three vias to reduce the parasitic inductance.
- Include a Kelvin VDD connection, or separate from VIN connection (bypass input capacitors); add a
 placeholder for a filter resistor between the VDD pin and the input bus. Place the VDD decoupling capacitor
 near the VDD pin and on the same side as the device to avoid the use of vias. Use wide and short traces for
 the connection from the VDD pin to the capacitor and from the capacitor to the power pad of the device. If
 vias are not avoidable, use at least three vias to reduce the parasitic inductance.
- · Maintain the FB trace away from BOOT and SW traces.
- Minimize the area of switch node.
- Use a single ground. Do not use separate signal and power ground.
- Use 3 × 7 thermal vias as suggested in Land Pattern Data in Mechanical, Packaging, and Orderable Information.

10.2 Layout Example

The TPS56221EVM layout is shown in Figure 25 through Figure 30 for reference.





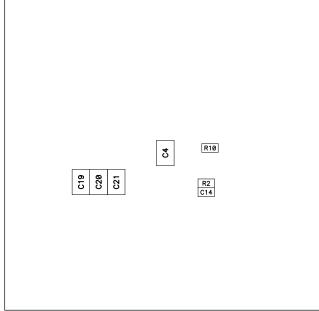


Figure 26. TPS56221EVM Bottom Assembly Drawing (Bottom view)

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22

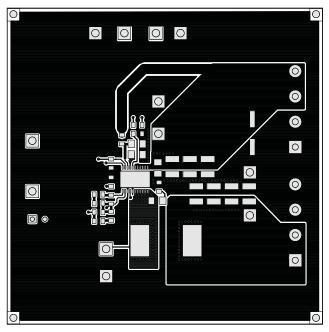


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Layout Example (continued)



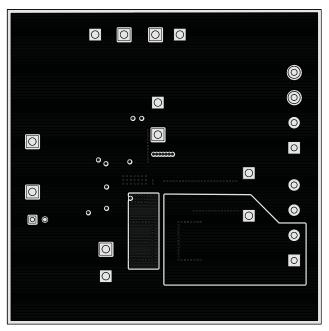
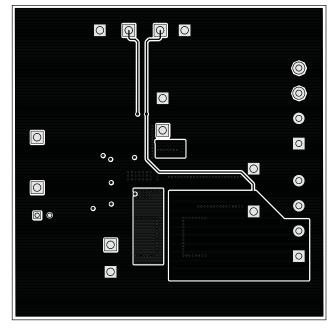


Figure 27. TPS56221EVM Top Copper (Top View)

Figure 28. TPS56221EVM Internal 1 (Top View)





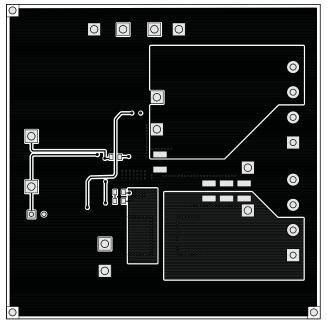


Figure 30. TPS56221EVM Bottom Copper (Top View)



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11 Device and Documentation Support

11.1 Device Support

11.1.1 Third-Party Products Disclaimer

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11.2 Trademarks

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11.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: TPS56221

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PACKAGE OPTION ADDENDUM

8-Feb-2016

PACKAGING INFORMATION

Package Type Package Pins Package Lead/Ball Finish Orderable Device Status Eco Plan MSL Peak Temp Op Temp (°C) **Device Marking** Samples Qty Drawing (1) (2) (6) (3) ACTIVE LSON-CLIF CU NIPDAU Level-2-260C-1 YEAR TPS56221 TPS56221DQPR DQP 22 2500 Pb-Free (RoHS -40 to 125 Samples Exempt) Pb-Free (RoHS CU NIPDAU TPS56221DQPT **ACTIVE** LSON-CLIP DQP Level-2-260C-1 YEAR TPS56221 22 250 -40 to 125 Exempt)

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight

in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width

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Addendum-Page 1



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PACKAGE OPTION ADDENDUM

ww.ti.com 8-Feb-2016

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

Addendum-Page 2

Datasheet of TPS56221DQPT - IC REG BUCK ADJ 25A SYNC 22SON

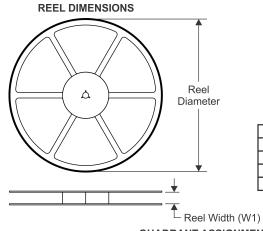
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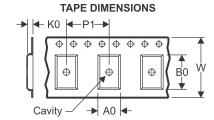


PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

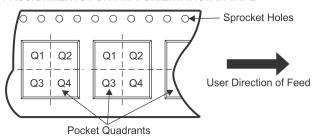




			component width
	Dimonoion	decimand to	 aanananant lanath

- B0 Dimension designed to accommodate the component length
- K0 Dimension designed to accommodate the component thickness
- W Overall width of the carrier tape
- P1 Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

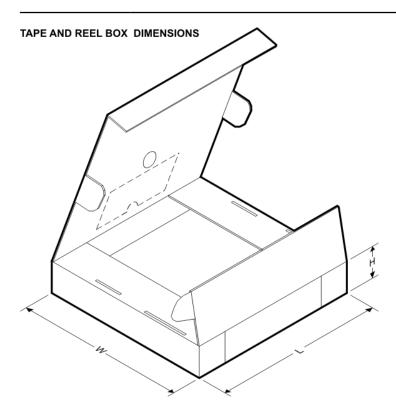
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS56221DQPR	LSON- CLIP	DQP	22	2500	330.0	12.4	5.3	6.3	1.8	8.0	12.0	Q1
TPS56221DQPT	LSON- CLIP	DQP	22	250	180.0	12.4	5.3	6.3	1.8	8.0	12.0	Q1

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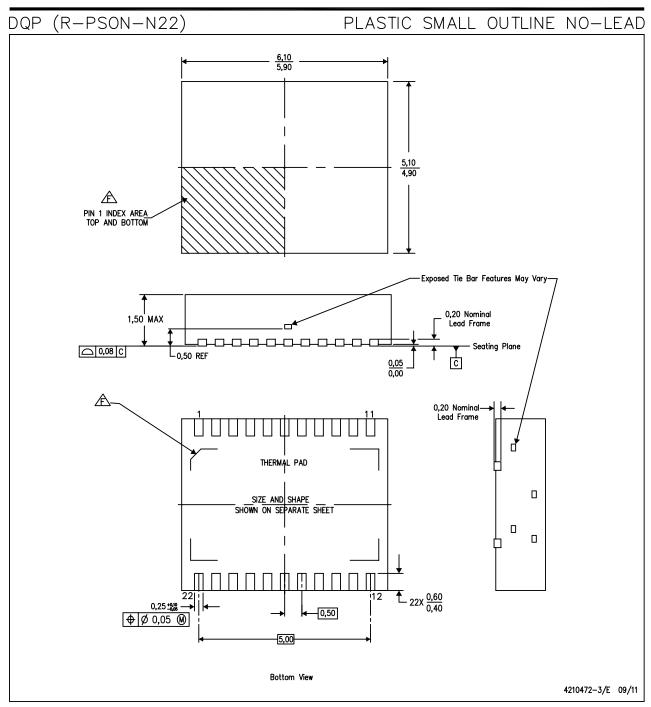


*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS56221DQPR	LSON-CLIP	DQP	22	2500	367.0	367.0	35.0
TPS56221DQPT	LSON-CLIP	DQP	22	250	210.0	185.0	35.0



MECHANICAL DATA



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Small Outline No-Lead (SON) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.

Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.





THERMAL PAD MECHANICAL DATA

DQP (R-PSON-N22)

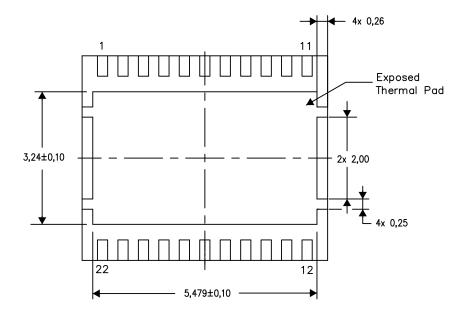
PLASTIC SMALL OUTLINE NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

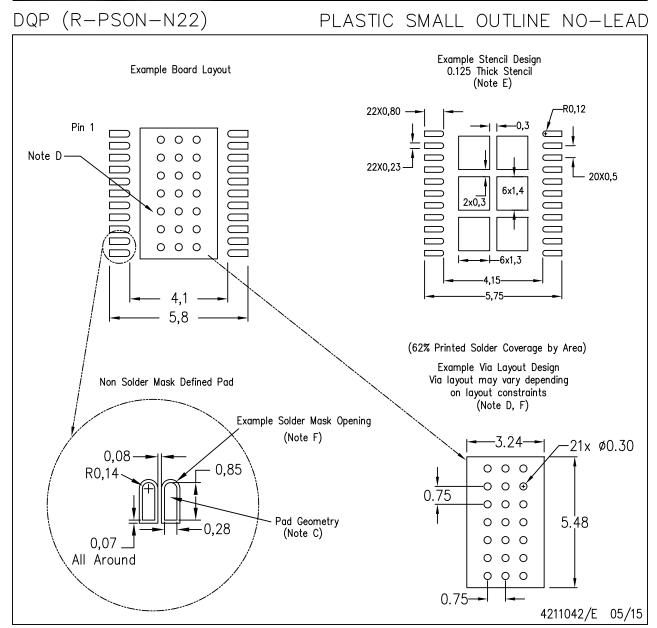
4211024-3/H 08/15

NOTE: All linear dimensions are in millimeters





LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.





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